

## GNSS LOW NOISE AMPLIFIER GaAs MMIC

### ■ GENERAL DESCRIPTION

The NJG1143UA2 is a low noise amplifier GaAs MMIC designed for GNSS (Global navigation Satellite Systems).

The NJG1143UA2 is featured very small size, low noise figure, high gain and low current consumption. The NJG1143UA2 operates from 1.5V to 3.6V single voltage between -40 and 105°C, has stand-by mode to save the supply current, and requires only three external components. The NJG1143UA2 has an on-chip ESD protection. The NJG1143UA2 is available in a very small, lead-free, halogen-free, 1.0mm x 1.0mm x 0.37 mm, 6-pin EPFFP6-A2 package.

### ■ PACKAGE OUTLINE



NJG1143UA2

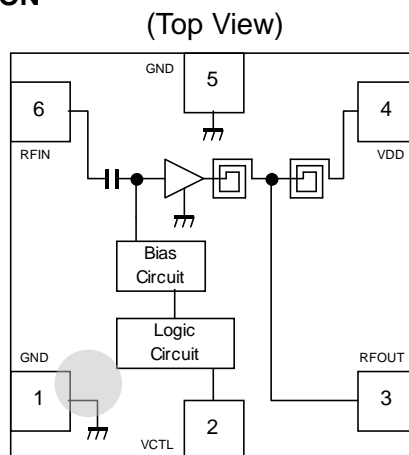
### ■ APPLICATION

GNSS applications like GPS, Galileo, GLONASS and COMPASS

### ■ FEATURES

- Low supply voltage +2.85V typ. (+1.5V to +3.6V)
- Low control voltage +1.8V typ. (+1.5V to +3.6V)
- Low current consumption 4.0mA typ. @V<sub>DD</sub>=2.85V, V<sub>CTL</sub>=1.8V
- High gain 7μA typ. @V<sub>DD</sub>=2.85V, V<sub>CTL</sub>=0V, Stand-by mode
- Low noise figure 20.0dB typ. @V<sub>DD</sub>=2.85V, V<sub>CTL</sub>=1.8V, f=1575MHz
- Input power at 1dB gain compression point 0.70dB typ. @V<sub>DD</sub>=2.85V, V<sub>CTL</sub>=1.8V, f=1575MHz
- High input IP3 -16.5dBm typ. @V<sub>DD</sub>=2.85V, V<sub>CTL</sub>=1.8V, f=1575MHz
- Stand-by function -2.0dBm typ. @V<sub>DD</sub>=2.85V, V<sub>CTL</sub>=1.8V, f=1575+1575.1MHz
- Small package size EPFFP-A2 (Package size: 1.0mmx1.0mmx0.37mm typ.)
- Integrated ESD protection circuit
- Lead-free and halogen-free, MSL1

### ■ PIN CONFIGURATION



#### Pin Connection

1. GND
2. VCTL
3. RFOUT
4. VDD
5. GND
6. RFIN

### ■ TRUTH TABLE

“H”=V<sub>CTL</sub>(H), “L”=V<sub>CTL</sub>(L)

VCTL	LNA Mode
H	Active mode
L	Stand-by mode

Note: Specifications and description listed in this datasheet are subject to change without notice.

# NJG1143UA2

## ■ ABSOLUTE MAXIMUM RATINGS

$T_a=+25^{\circ}\text{C}$ ,  $Z_s=Z_i=50\Omega$

PARAMETERS	SYMBOL	CONDITIONS	RATINGS	UNITS
Supply voltage	$V_{DD}$		5.0	V
Control voltage	$V_{CTL}$		5.0	V
Input power	$P_{IN}$	$V_{DD}=2.85\text{V}$	+15	dBm
Power dissipation	$P_D$	4-layer FR4 PCB with through-hole (101.5mmx114.5mm), $T_j=150^{\circ}\text{C}$	590	mW
Operating temperature	$T_{opr}$		-40 to +105	$^{\circ}\text{C}$
Storage temperature	$T_{stg}$		-55 to +150	$^{\circ}\text{C}$

## ■ ELECTRICAL CHARACTERISTICS 1 (DC)

(General conditions:  $T_a=+25^{\circ}\text{C}$ ,  $Z_s=Z_i=50\Omega$ )

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNIT
Supply Voltage	$V_{DD}$	VDD Terminal	1.5	-	3.6	V
Control Voltage (High)	$V_{CTL(H)}$	VCTL Terminal	1.5	1.8	3.6	V
Control Voltage (Low)	$V_{CTL(L)}$	VCTL Terminal	0	0	0.3	V
Supply Current 1	$I_{DD1}$	Active mode VDD Terminal $V_{DD}=2.85\text{V}$ , $V_{CTL}=1.8\text{V}$	-	4.0	6.5	mA
Supply Current 2	$I_{DD2}$	Active mode VDD Terminal $V_{DD}=1.8\text{V}$ , $V_{CTL}=1.8\text{V}$	-	3.0	4.7	mA
Supply Current 3	$I_{DD3}$	Stand-by mode VDD Terminal $V_{DD}=2.85\text{V}$ , $V_{CTL}=0\text{V}$	-	7.0	15.0	$\mu\text{A}$
Supply Current 4	$I_{DD4}$	Stand-by mode VDD Terminal $V_{DD}=1.8\text{V}$ , $V_{CTL}=0\text{V}$	-	4.0	10.0	$\mu\text{A}$
Control Current	$I_{CTL}$	$V_{CTL}=1.8\text{V}$ , VCTL Terminal	-	5.0	12.0	$\mu\text{A}$

## ■ ELECTRICAL CHARACTERISTICS 2 (RF, $V_{DD}=2.85V$ )

(General conditions:  $V_{DD}=2.85V$ ,  $V_{CTL}=1.8V$ , Freq=1.575GHz,  $T_a=+25^{\circ}C$ ,  $Z_s=Z_l=50\Omega$ , with application circuit)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNIT
Small Signal Gain 1	Gain1		17.5	20.0	22.0	dB
Noise Figure 1	NF1	Exclude PCB and connector Losses (0.08dB)	-	0.70	0.95	dB
Input Power at 1dB Gain Compression Point 1	P-1dB(IN) <sub>1</sub>		-19.0	-16.5	-	dBm
Input 3rd Order Intercept Point 1	IIP3 <sub>1</sub>	2 tone, 100k spacing Pin=-34dBm	-6.0	-2.0	-	dBm
RF Input Port VSWR 1	VSWR <sub>i1</sub>		-	1.5	2.0	
RF Output Port VSWR 1	VSWR <sub>o1</sub>			1.5	2.0	

## ■ ELECTRICAL CHARACTERISTICS 3 (RF, $V_{DD}=1.8V$ )

(General conditions:  $V_{DD}=1.8V$ ,  $V_{CTL}=1.8V$ , Freq=1.575GHz,  $T_a=+25^{\circ}C$ ,  $Z_s=Z_l=50\Omega$ , with application circuit)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNIT
Small Signal Gain 2	Gain2		16.5	19.0	21.0	dB
Noise Figure 2	NF2	Exclude PCB and connector Losses (0.08dB)	-	0.75	1.10	dB
Input Power at 1dB Gain Compression Point 2	P-1dB(IN) <sub>2</sub>		-22.0	-19.5	-	dBm
Input 3rd Order Intercept Point 2	IIP3 <sub>2</sub>	2 tone, 100k spacing Pin=-34dBm	-10.0	-6.0	-	dBm
RF Input Port VSWR 2	VSWR <sub>i2</sub>		-	1.5	2.3	
RF Output Port VSWR 2	VSWR <sub>o2</sub>			1.3	1.7	

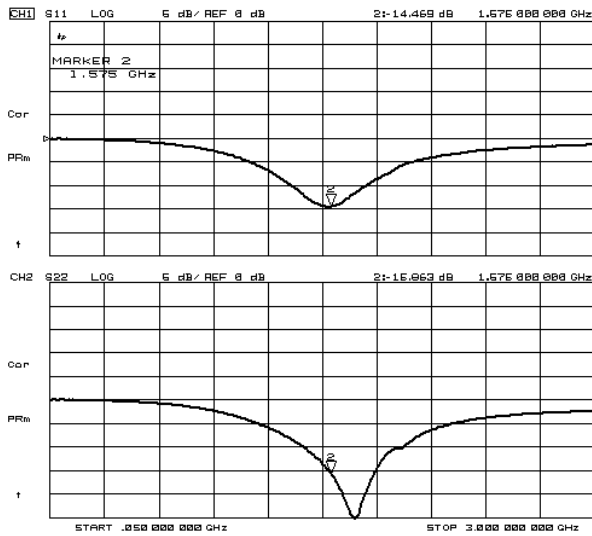
# NJG1143UA2

## ■ TERMINAL INFORMATION

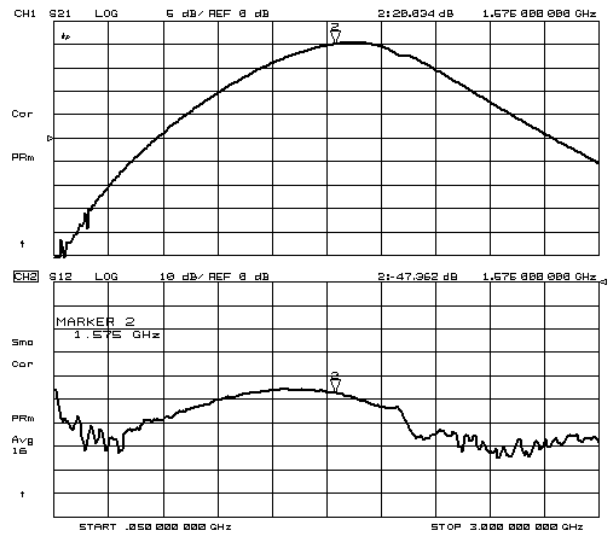
No.	SYMBOL	DESCRIPTION
1	GND	Ground terminal. These terminals should be connected to the ground plane as close as possible for excellent RF performance.
2	VCTL	Control voltage terminal. Inputting a logic-high, the LNA turn at LNA active mode. Inputting a logic-low, the LNA turn at stand-by mode.
3	RFOUT	RF output terminal. Requires an external capacitor C1. The capacitor C1 is not only a matching component, but also a DC blocking capacitor.
4	VDD	Supply voltage terminal. Bypass to ground with capacitor C2 as close as possible to the IC.
5	GND	Ground terminal. These terminals should be connected to the ground plane as close as possible for excellent RF performance.
6	RFIN	RF input terminal. Requires a matching inductor L1. Integrated a DC blocking capacitor.

## ELECTRICAL CHARACTERISTICS

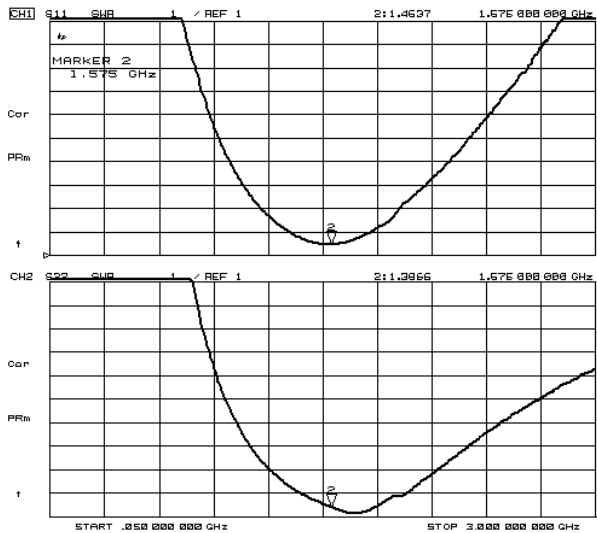
Conditions:  $V_{DD}=2.85V$ ,  $V_{CTL}=1.8V$ ,  $T_a=+25^{\circ}C$ ,  $Z_s=Z_l=50\Omega$ , with application circuit



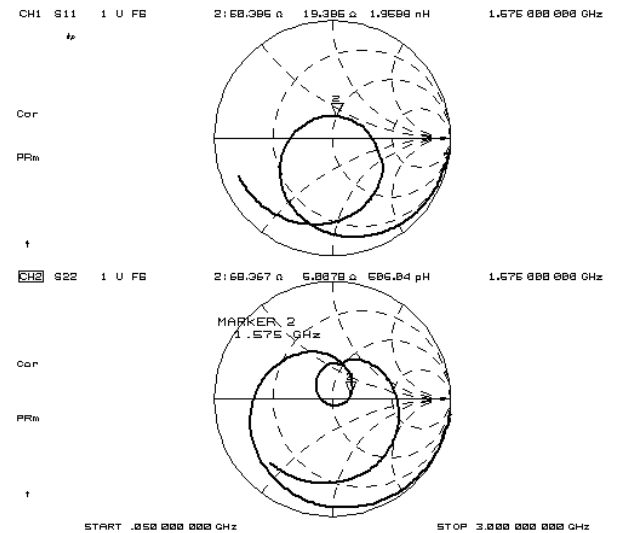
S11, S22



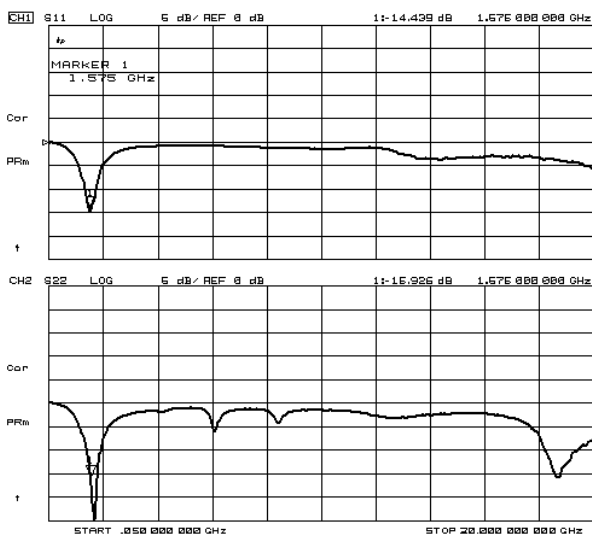
S21, S12



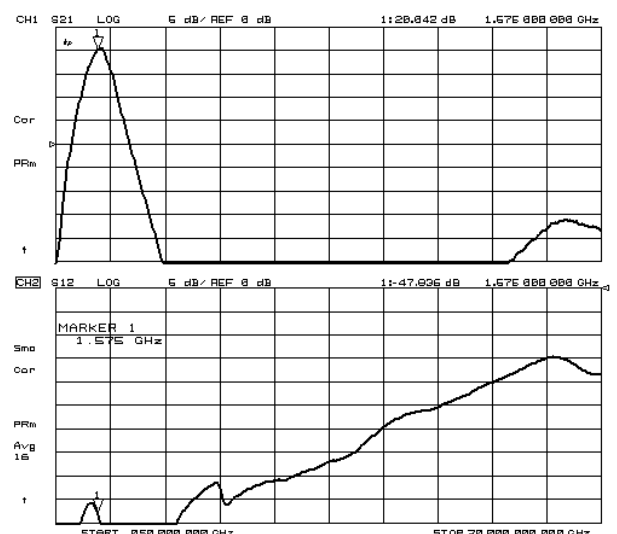
VSWR



Zin, Zout



S11, S22 (f=50MHz~20GHz)

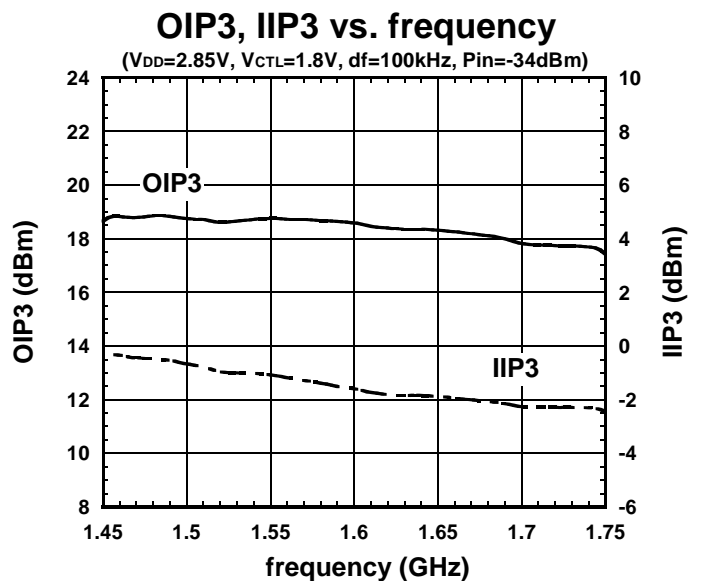
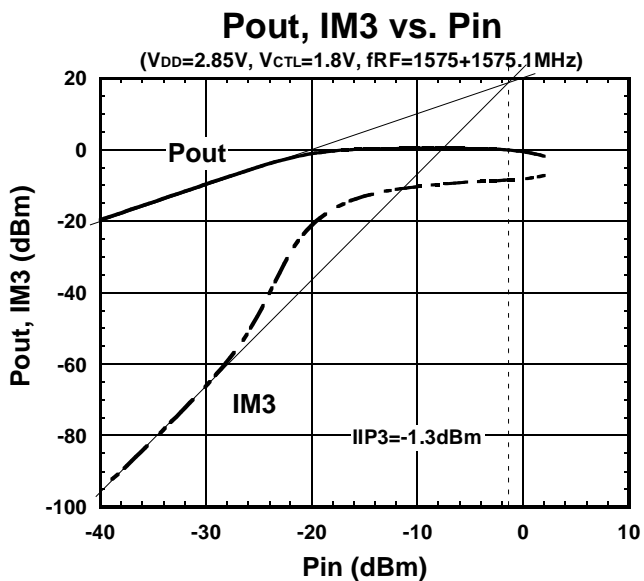
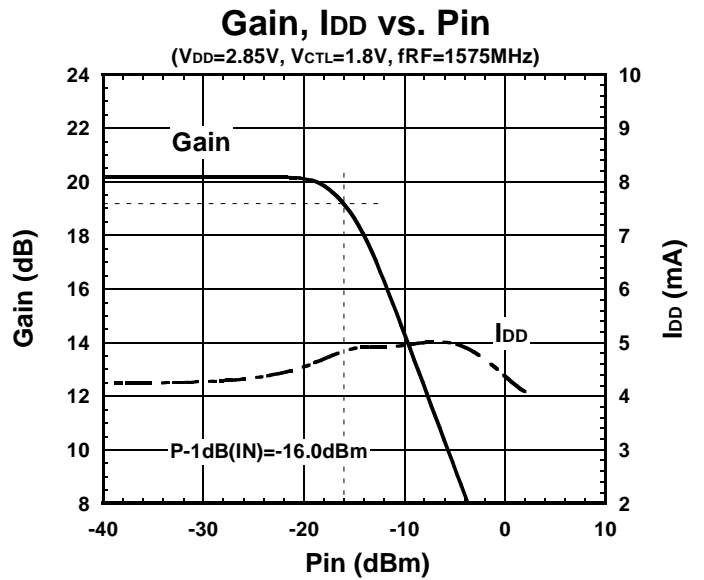
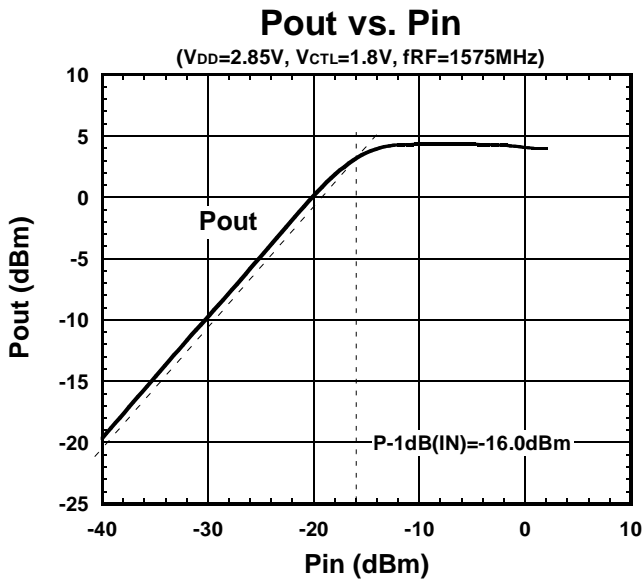
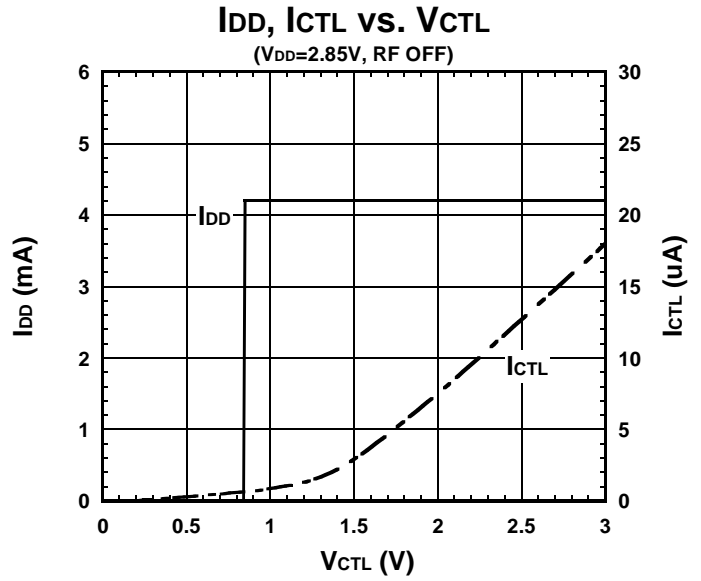
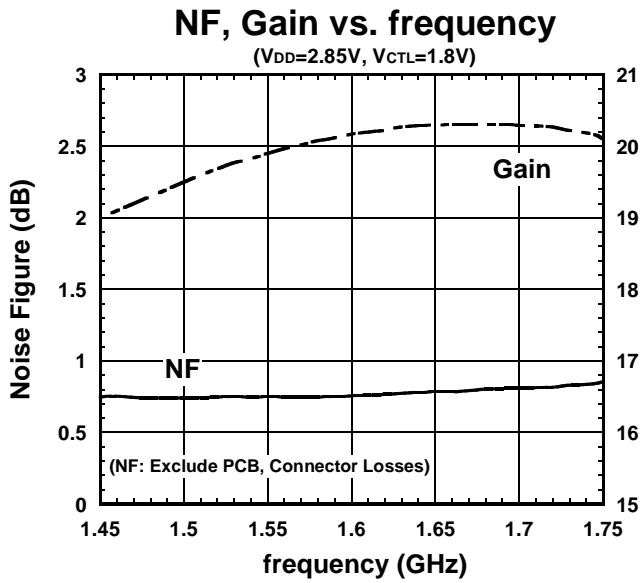


S21, S12 (f=50MHz~20GHz)

# NJG1143UA2

## ELECTRICAL CHARACTERISTICS

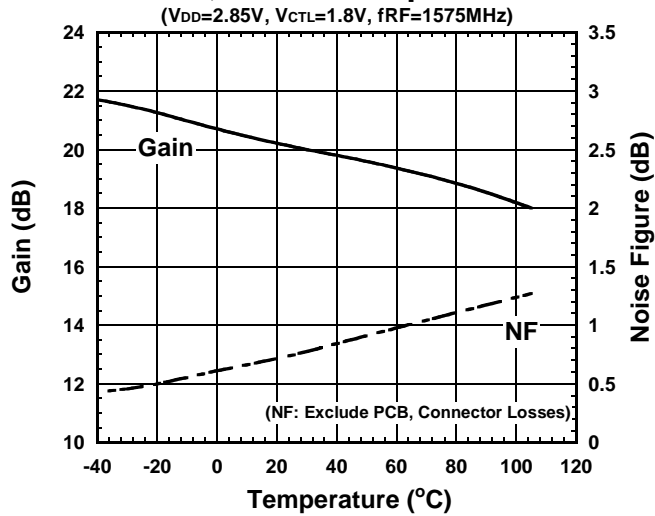
Conditions:  $V_{DD}=2.85V$ ,  $V_{CTL}=1.8V$ ,  $T_a=+25^{\circ}C$ ,  $Z_s=Z_l=50\Omega$ , with application circuit



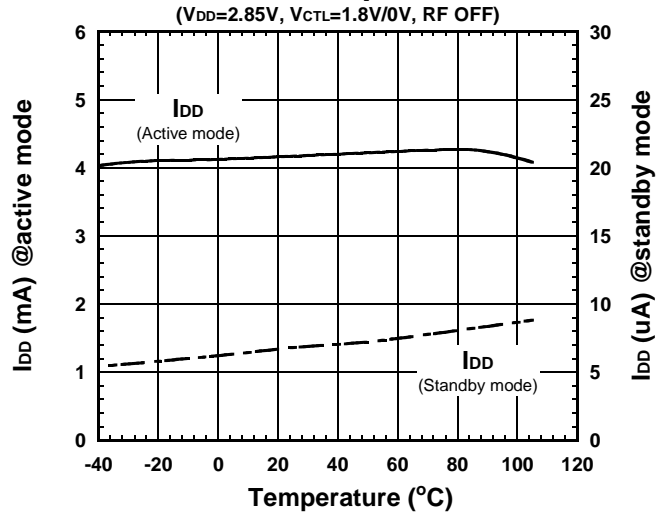
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Conditions:  $V_{DD}=2.85V$ ,  $V_{CTL}=1.8V$ ,  $T_a=+25^\circ C$ ,  $Z_s=Z_l=50\Omega$ , with application circuit

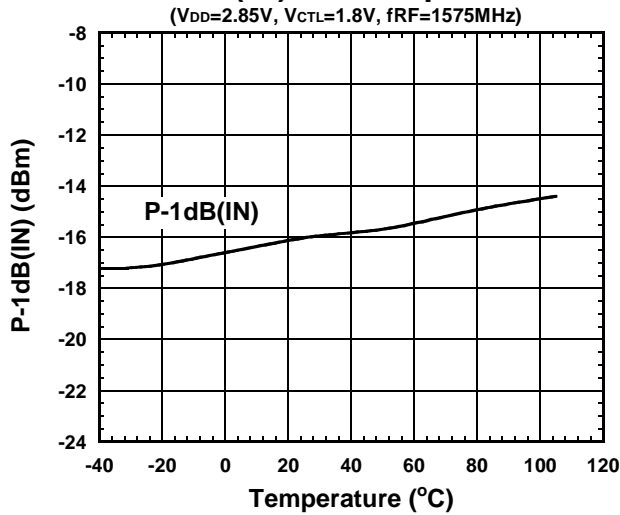
### Gain, NF vs. Temperature



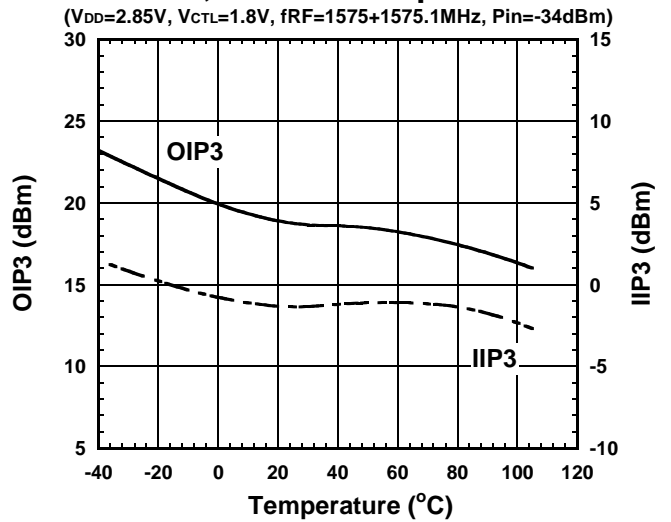
### I<sub>DD</sub> vs. Temperature



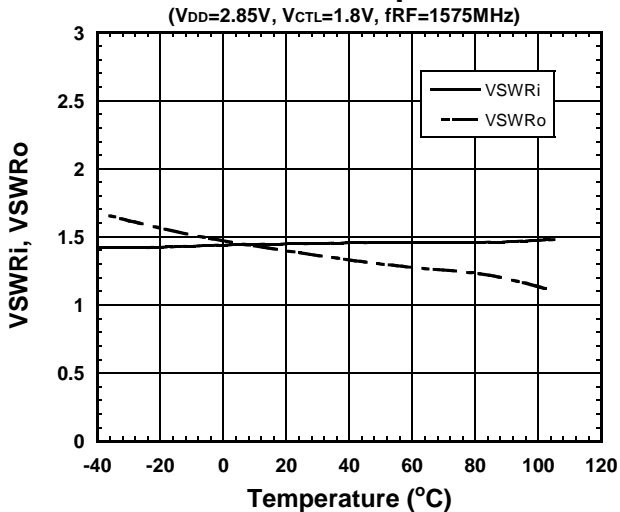
### P-1dB(IN) vs. Temperature



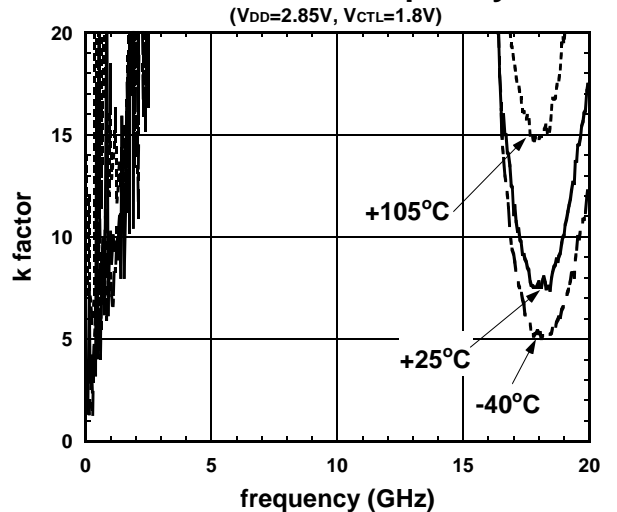
### OIP3, IIP3 vs. Temperature



### VSWR vs. Temperature



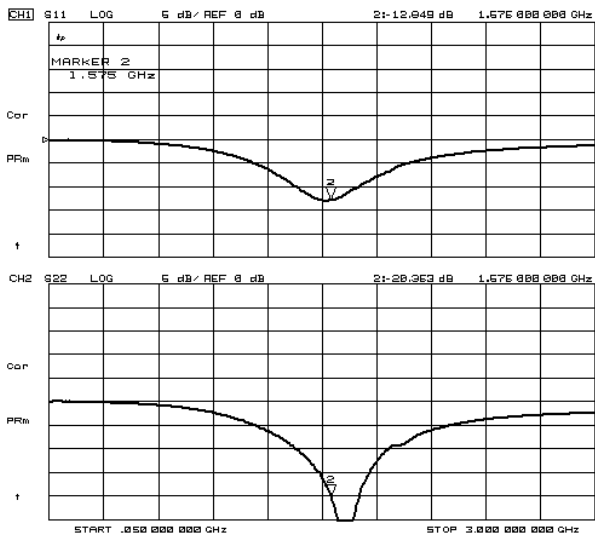
### k factor vs. frequency



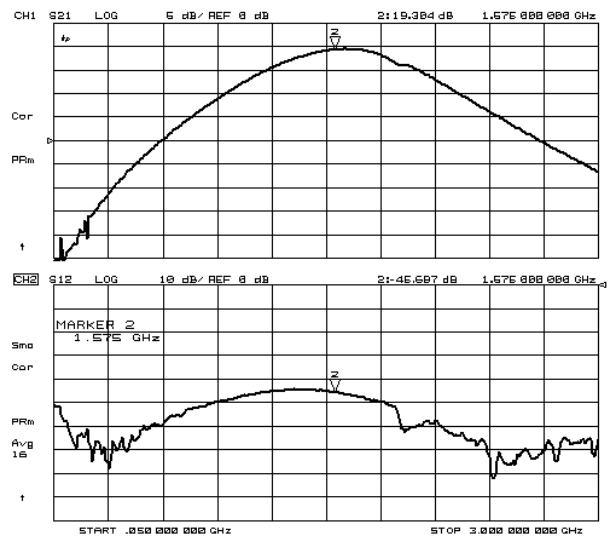
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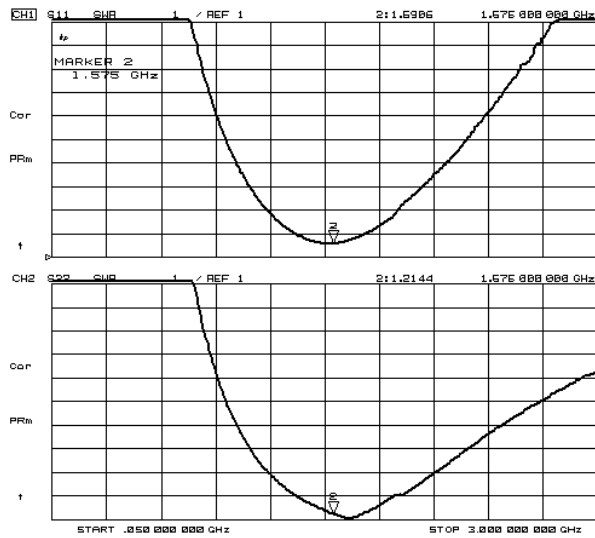
Conditions:  $V_{DD}=1.8V$ ,  $V_{CTL}=1.8V$ ,  $T_a=+25^{\circ}C$ ,  $Z_s=Z_l=50\Omega$ , with application circuit



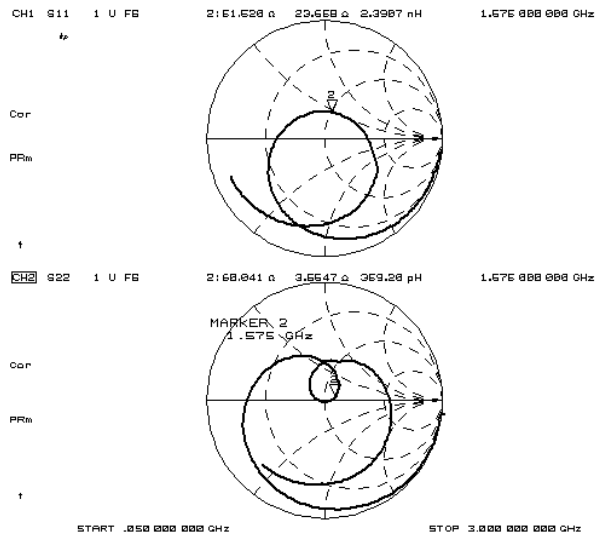
S11, S22



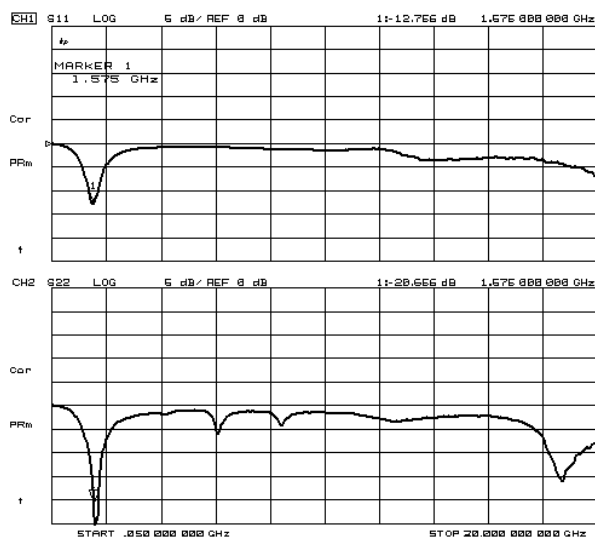
S21, S12



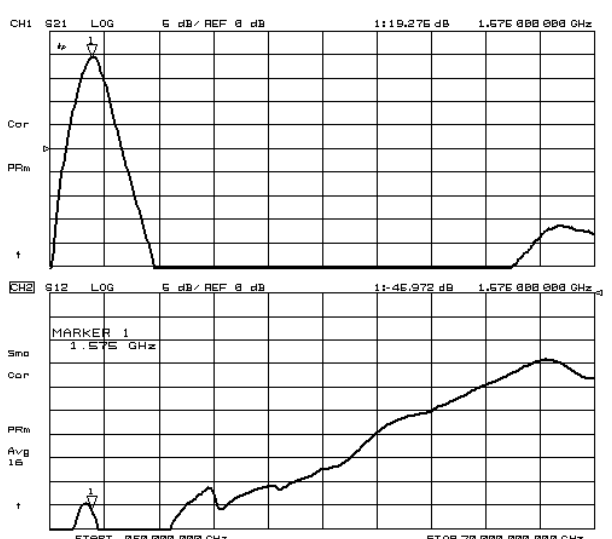
VSWR



Zin, Zout



S11, S22 (f=50MHz~20GHz)

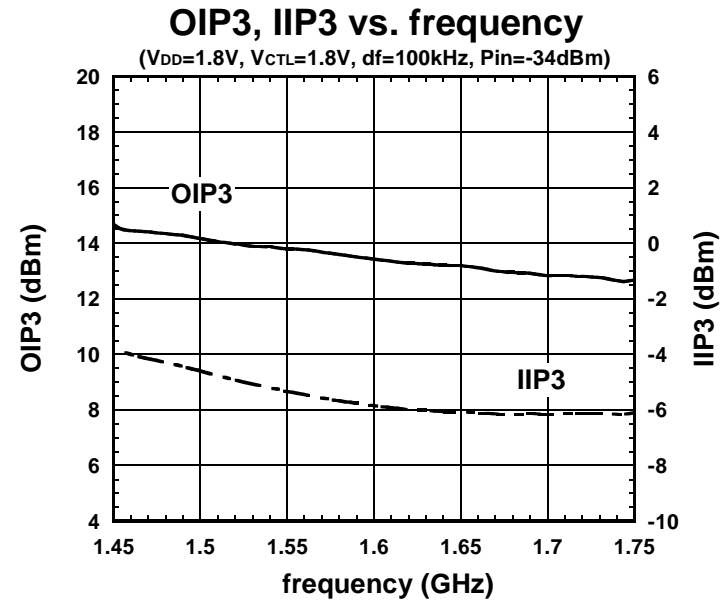
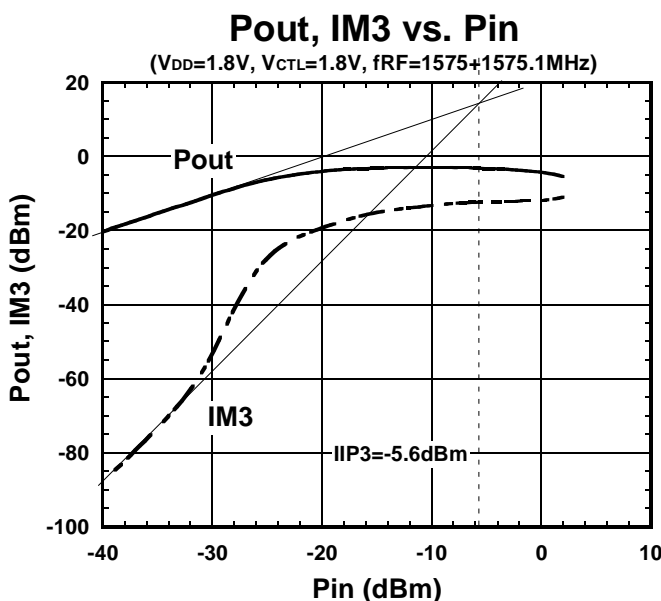
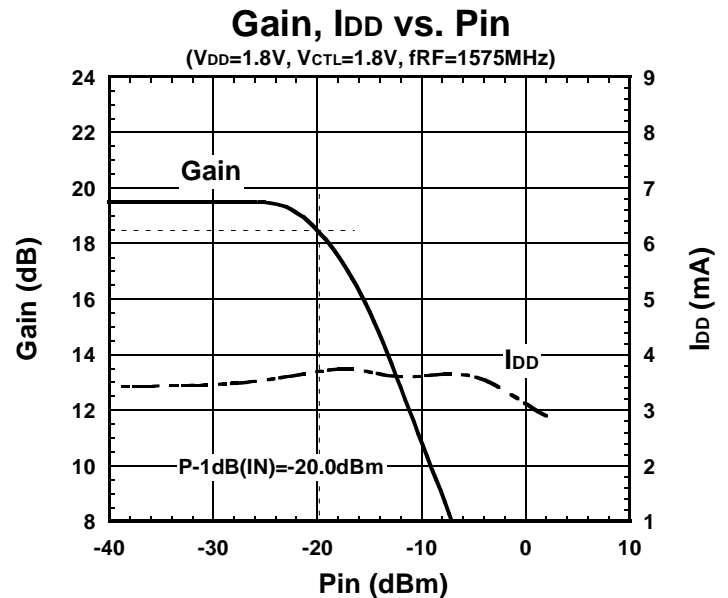
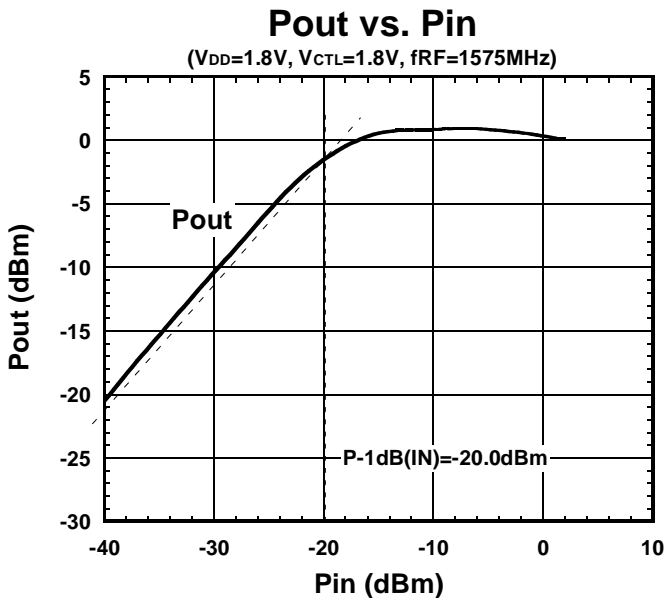
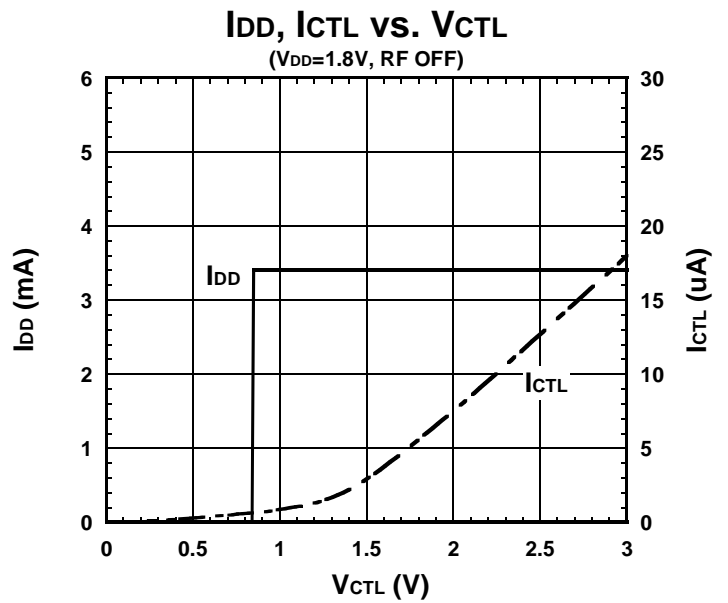
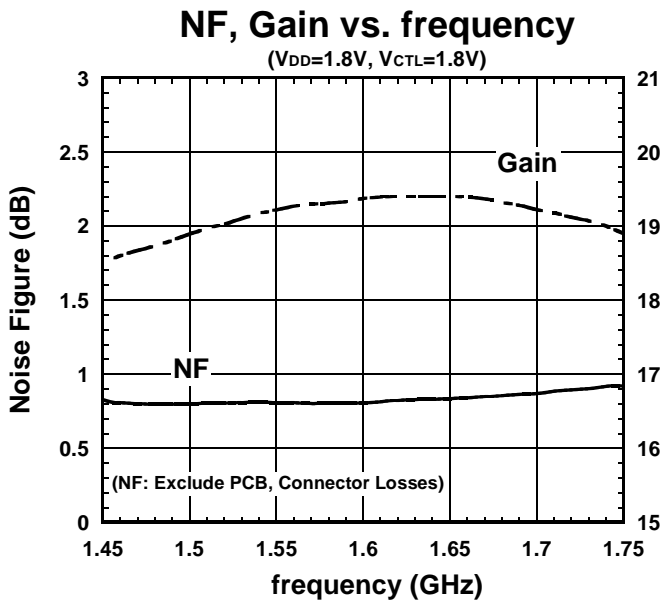


S21, S12 (f=50MHz~20GHz)



## ELECTRICAL CHARACTERISTICS

Conditions:  $V_{DD}=1.8V$ ,  $V_{CTL}=1.8V$ ,  $T_a=+25^{\circ}C$ ,  $Z_s=Z_l=50\Omega$ , with application circuit

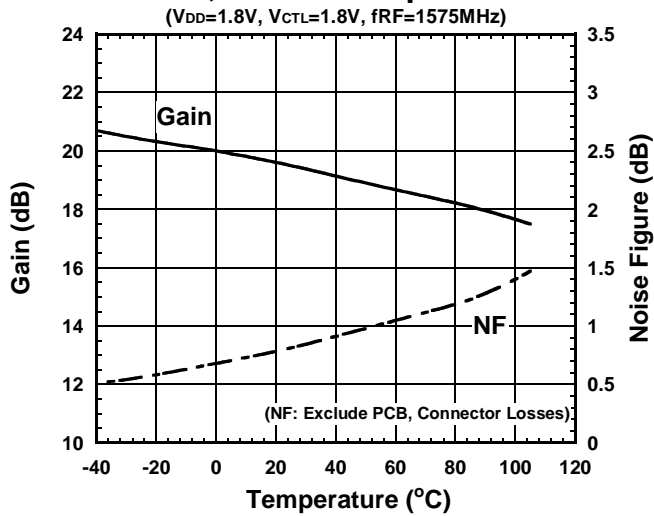


# NJG1143UA2

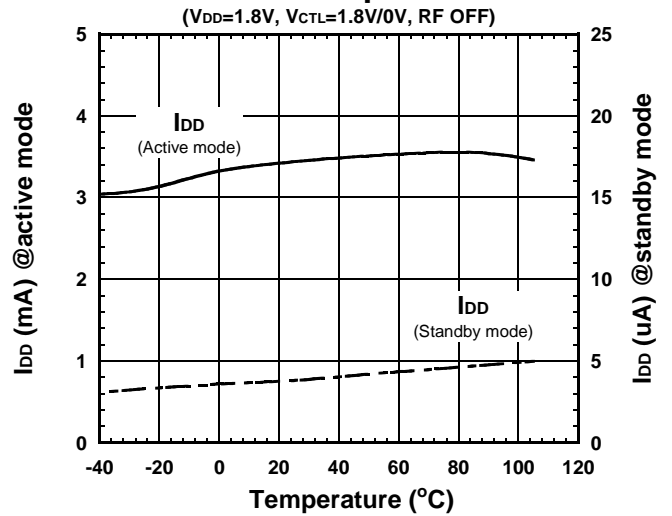
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Conditions:  $V_{DD}=1.8V$ ,  $V_{CTL}=1.8V$ ,  $Z_s=Z_l=50\Omega$ , with application circuit

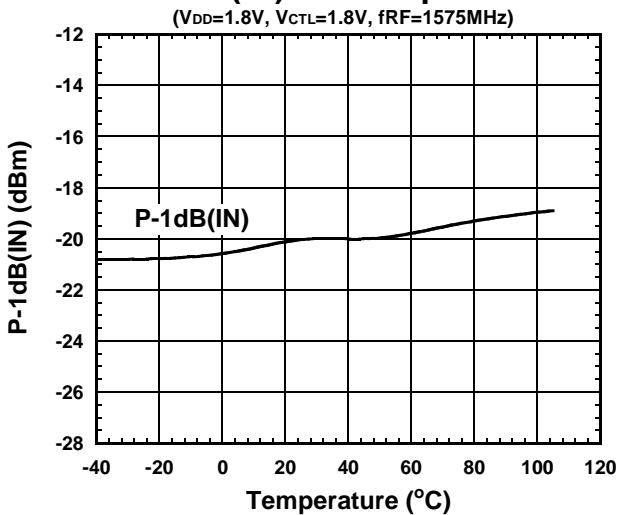
### Gain, NF vs. Temperature



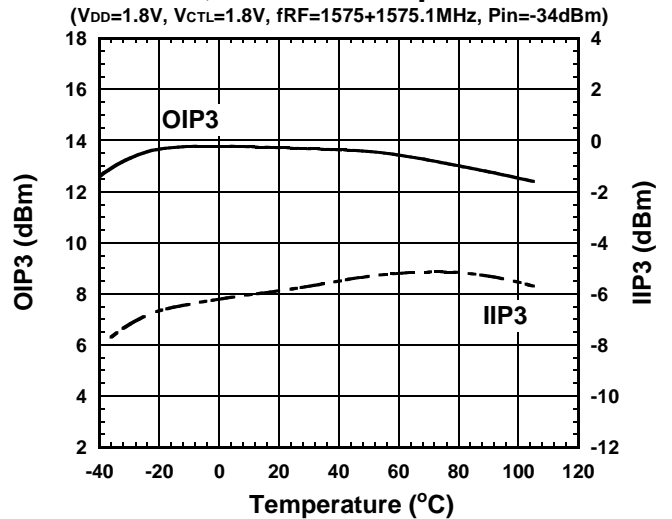
### I<sub>DD</sub> vs. Temperature



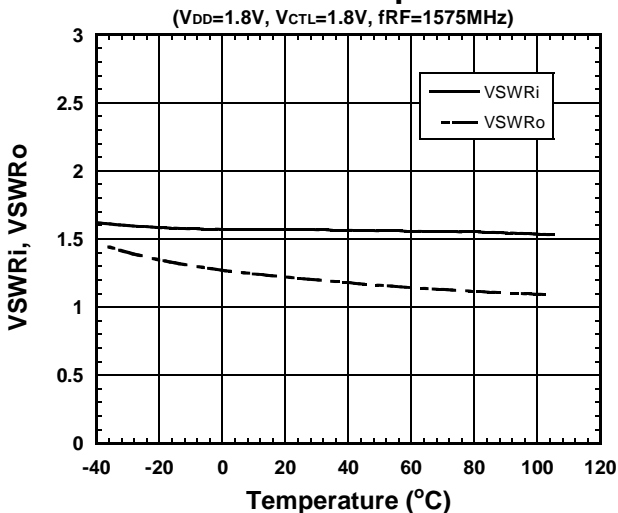
### P-1dB(IN) vs. Temperature



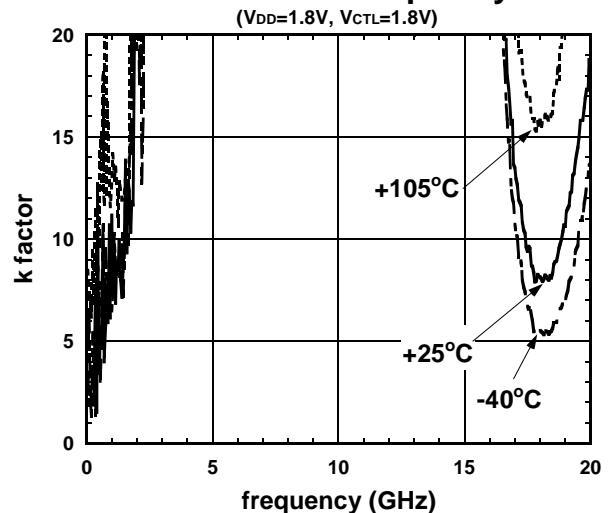
### OIP3, IIP3 vs. Temperature



### VSWR vs. Temperature

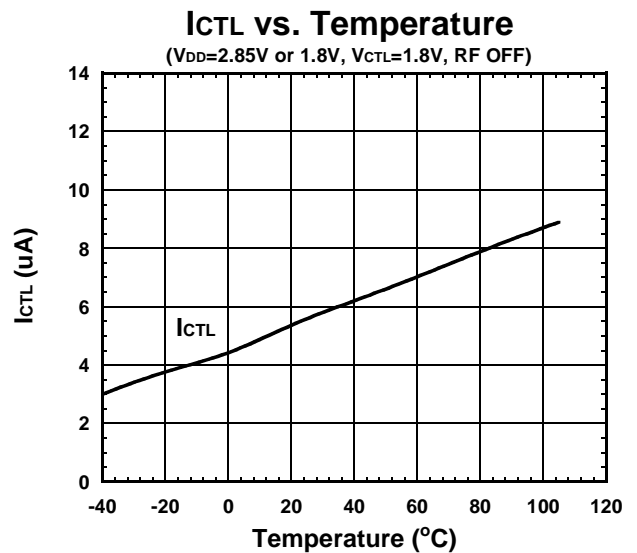
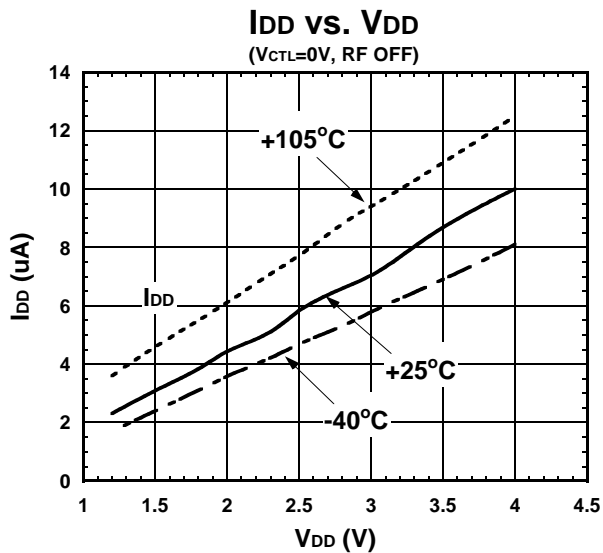
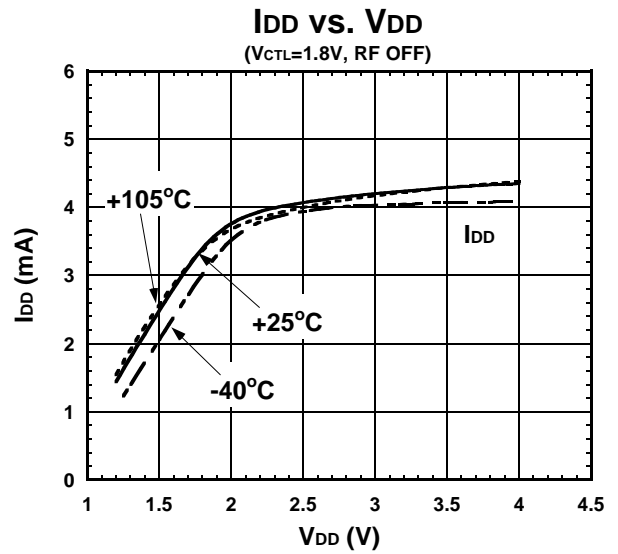
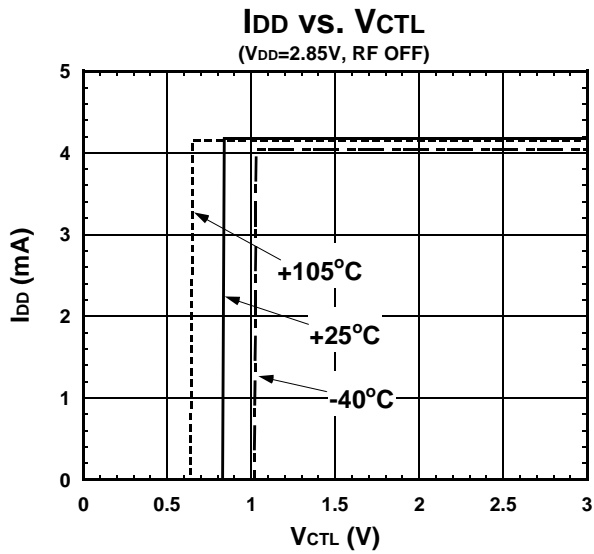


### k factor vs. frequency



## ELECTRICAL CHARACTERISTICS

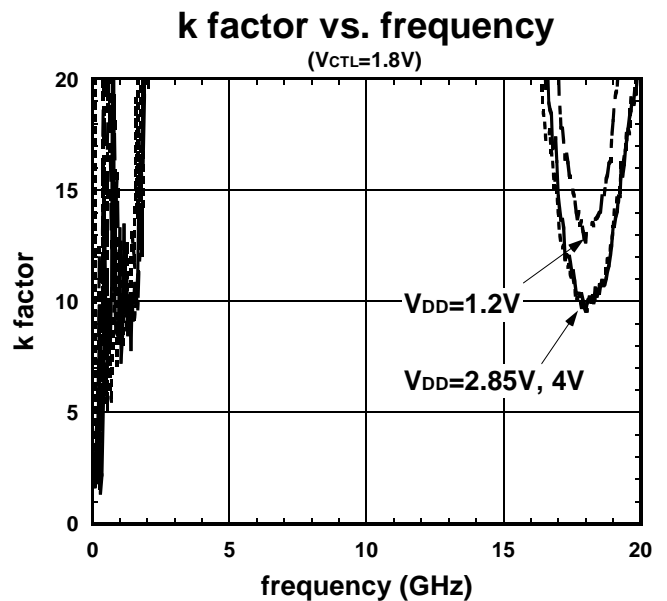
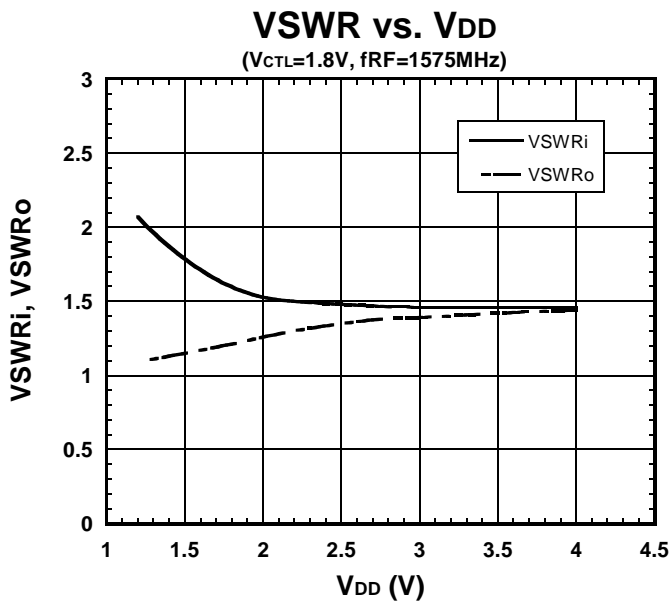
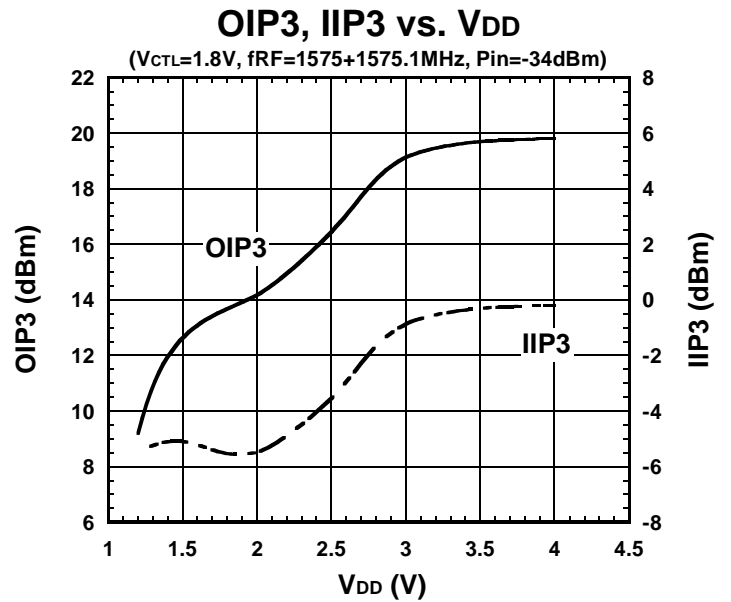
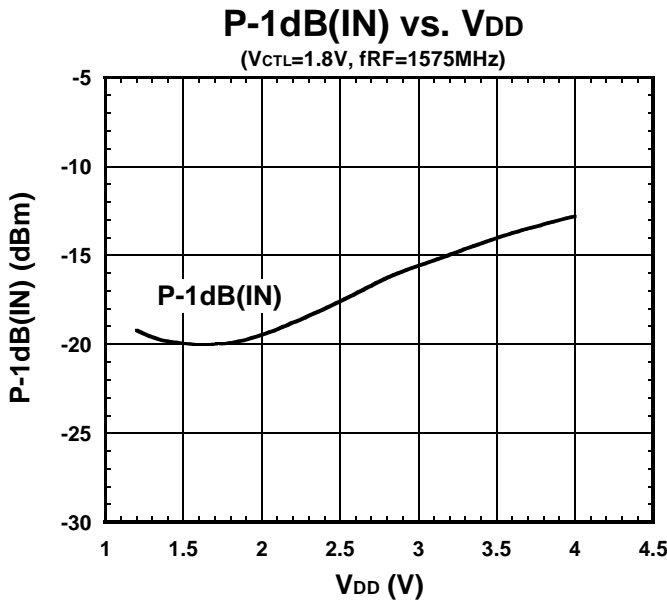
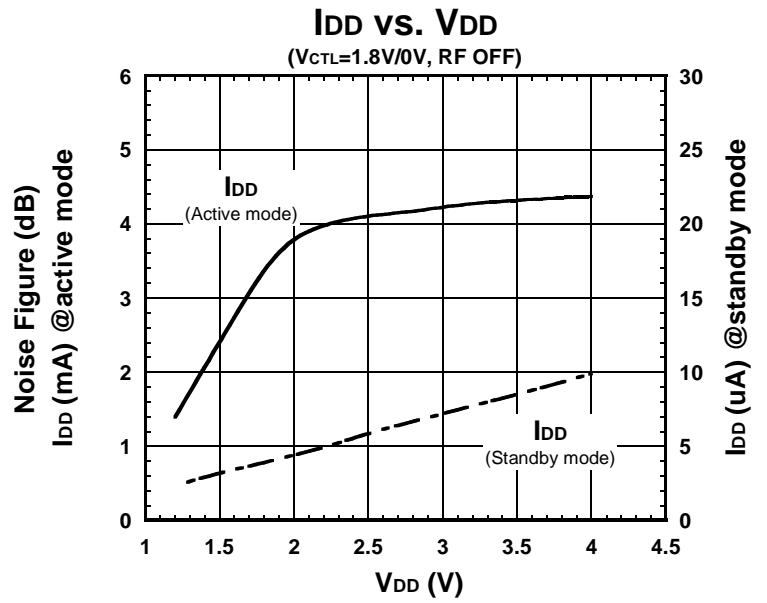
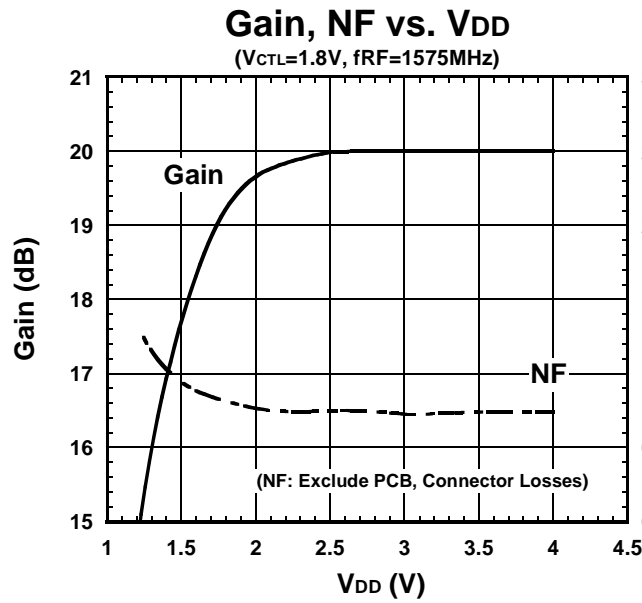
Conditions: RF OFF,  $Z_s=Z_l=50\Omega$ , with application circuit



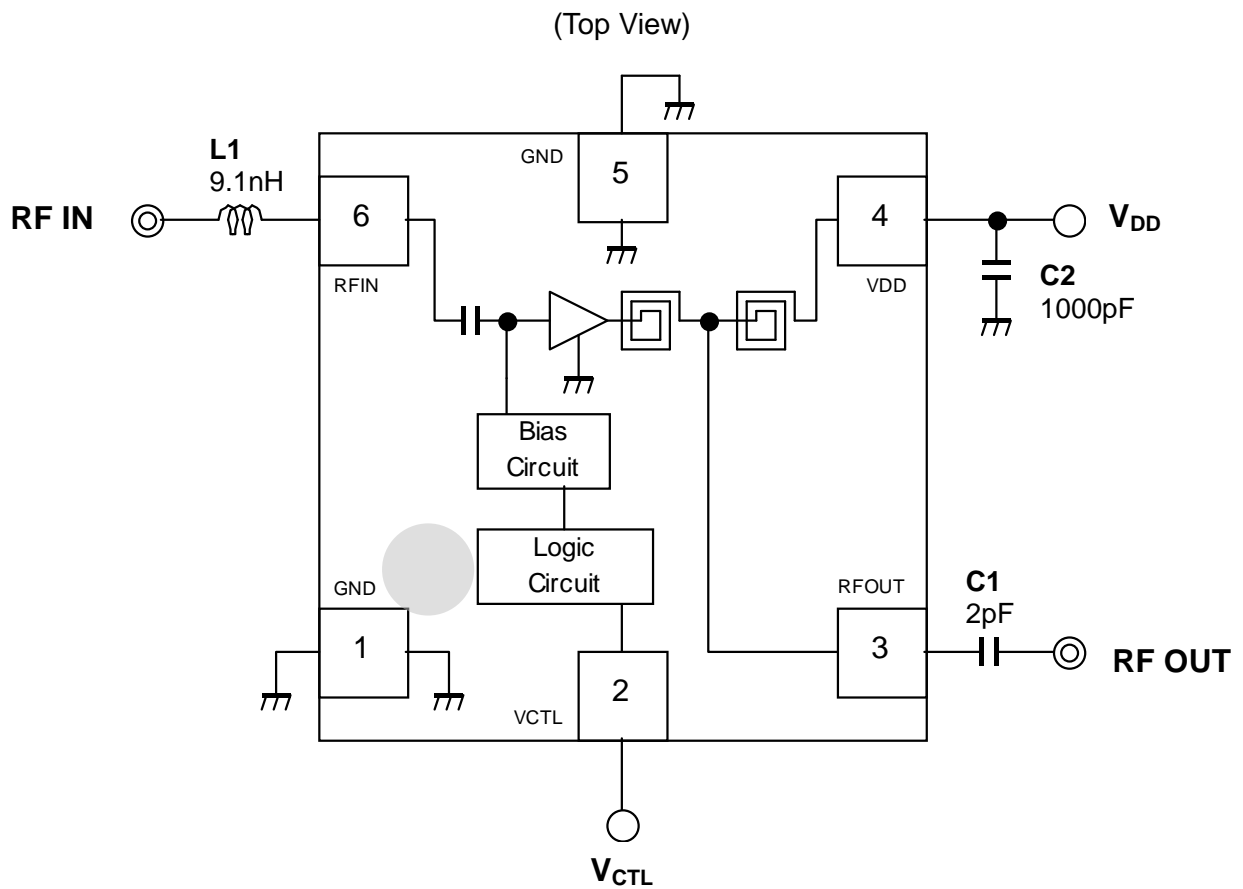
# NJG1143UA2

## ELECTRICAL CHARACTERISTICS

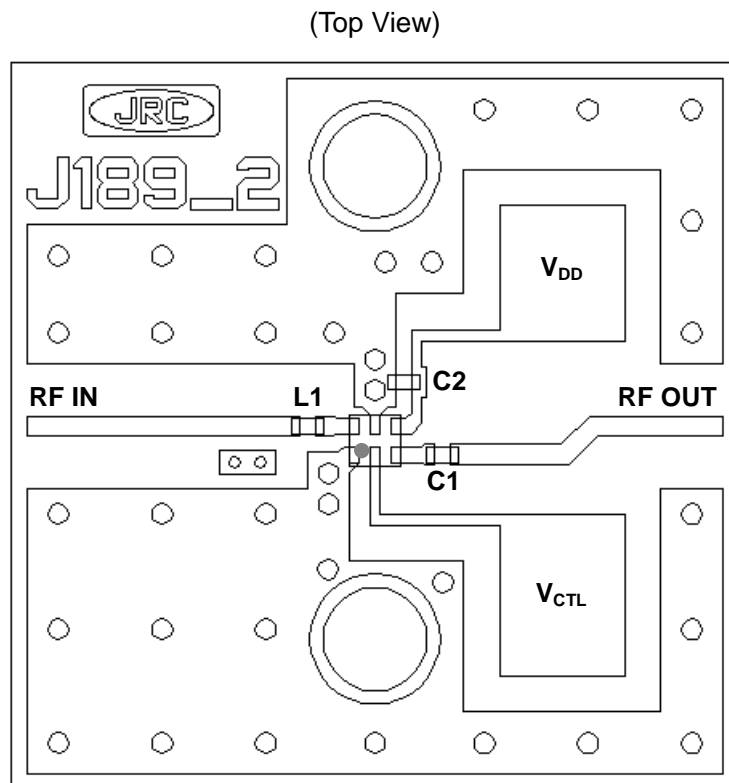
Condition:  $V_{CTL}=1.8V$ ,  $T_a=+25^{\circ}C$ ,  $Z_s=Z_l=50\Omega$ , with application circuit



## APPLICATION CIRCUIT



## TEST PCB LAYOUT



### Parts list

Parts ID	Manufacture
L1	LQP03T_02 Series (MURATA)
C1, C2	GRM03 Series (MURATA)

### PCB

Substrate: FR-4  
 Thickness: 0.2mm  
 Microstrip line width: 0.4mm ( $Z_0=50\Omega$ )  
 Size: 14.0mm x 14.0mm

# NJG1143UA2

## ■ NOISE FIGURE MEASUREMENT CONDITONS

### Measuring instruments

NF Analyzer : Agilent 8973A, 8975A

Noise Source : Agilent 346A

### Setting the NF analyzer

Measurement mode form

Device under test : Amplifier

System downconverter : off

Mode setup form

Sideband : LSB

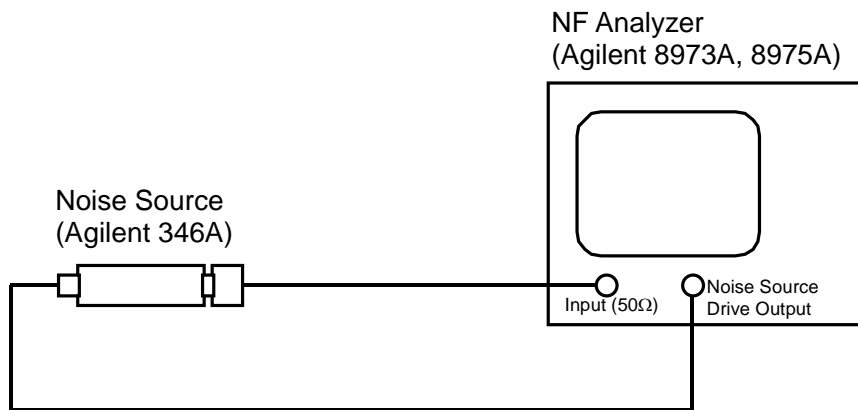
Averages : 16

Average mode : Point

Bandwidth : 4MHz

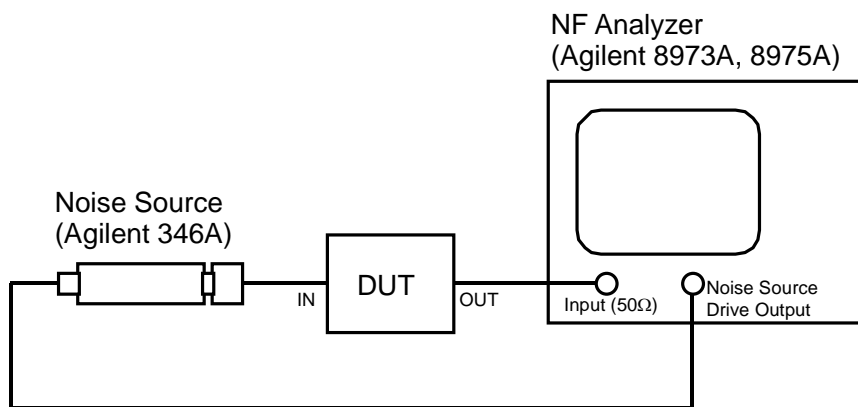
Loss comp : off

Tcold : setting the temperature of noise source (303.15K)



\* Noise source and NF analyzer are connected directly.

Calibration Setup



\* Noise source and DUT, DUT and NF analyzer are connected directly.

Measurement Setup

